



# TYN16-600RT

## SCR

Rev. 1 — 2 July 2012

Product data sheet

## 1. Product profile

### 1.1 General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 (TO-220AB) plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ( $T_{j(max)} = 150\text{ °C}$ ).

### 1.2 Features and benefits

- High junction operating temperature capability
- High thermal cycling performance
- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Very high current surge capability

### 1.3 Applications

- Ignition circuits
- Motor control
- Protection circuits e.g. SMPS inrush current
- Voltage regulation

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	-	600	V
$V_{RRM}$	repetitive peak reverse voltage		-	-	600	V
$I_{TSM}$	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25\text{ °C}$ ; $t_p = 10\text{ ms}$ ; see <a href="#">Figure 4</a> ; see <a href="#">Figure 5</a>	-	-	210	A
		half sine wave; $T_{j(init)} = 25\text{ °C}$ ; $t_p = 8.3\text{ ms}$	-	-	231	A
$T_j$	junction temperature		-	-	150	°C
$I_{T(AV)}$	average on-state current	half sine wave; $T_{mb} \leq 134\text{ °C}$ ; see <a href="#">Figure 3</a>	-	-	10.2	A
$I_{T(RMS)}$	RMS on-state current	half sine wave; $T_{mb} \leq 134\text{ °C}$ ; see <a href="#">Figure 1</a> ; see <a href="#">Figure 2</a>	-	-	16	A

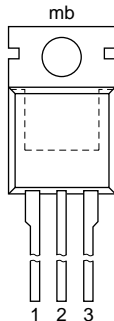



Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; see <a href="#">Figure 7</a>	-	4.5	25	mA
Dynamic characteristics						
dV <sub>D</sub> /dt	rate of rise of off-state voltage	V <sub>DM</sub> = 402 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	300	-	-	V/μs

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
3	G	gate		
mb	A	mounting base; connected to anode		
TO-220AB (SOT78)				

3. Ordering information

Table 3. Ordering information

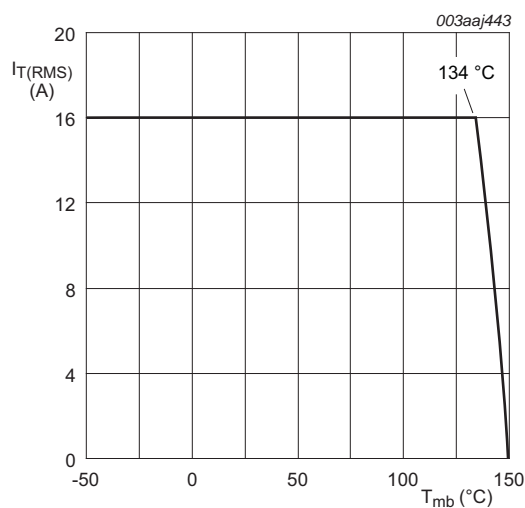
Type number	Package		
	Name	Description	Version
TYN16-600RT	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

## 4. Limiting values

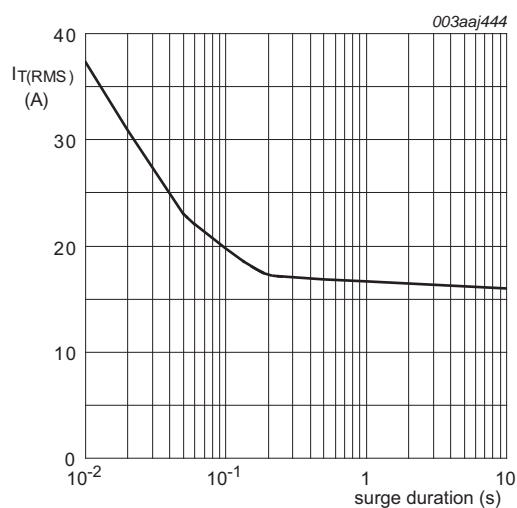
**Table 4. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	600	V
$V_{\text{RRM}}$	repetitive peak reverse voltage		-	600	V
$I_{\text{T(AV)}}$	average on-state current	half sine wave; $T_{\text{mb}} \leq 134\text{ °C}$ ; see <a href="#">Figure 3</a>	-	10.2	A
$I_{\text{T(RMS)}}$	RMS on-state current	half sine wave; $T_{\text{mb}} \leq 134\text{ °C}$ ; see <a href="#">Figure 1</a> ; see <a href="#">Figure 2</a>	-	16	A
$I_{\text{TSM}}$	non-repetitive peak on-state current	half sine wave; $T_{\text{j(init)}} = 25\text{ °C}$ ; $t_{\text{p}} = 10\text{ ms}$ ; see <a href="#">Figure 4</a> ; see <a href="#">Figure 5</a>	-	210	A
		half sine wave; $T_{\text{j(init)}} = 25\text{ °C}$ ; $t_{\text{p}} = 8.3\text{ ms}$	-	231	A
$I^2t$	$I^2t$ for fusing	$t_{\text{p}} = 10\text{ ms}$ ; sine-wave pulse	-	220.5	A <sup>2</sup> s
$di_{\text{T}}/dt$	rate of rise of on-state current	$I_{\text{T}} = 40\text{ A}$ ; $I_{\text{G}} = 200\text{ mA}$ ; $di_{\text{G}}/dt = 200\text{ mA}/\mu\text{s}$	-	50	A/ $\mu\text{s}$
$I_{\text{GM}}$	peak gate current		-	5	A
$V_{\text{RGM}}$	peak reverse gate voltage		-	5	V
$P_{\text{GM}}$	peak gate power		-	20	W
$P_{\text{G(AV)}}$	average gate power	over any 20 ms period	-	1	W
$T_{\text{stg}}$	storage temperature		-40	150	°C
$T_{\text{j}}$	junction temperature		-	150	°C



**Fig 1. RMS on-state current as a function of mounting base temperature; maximum values**



$f = 50\text{ Hz}$ ;  $T_{\text{mb}} = 134\text{ °C}$

**Fig 2. RMS on-state current as a function of surge duration; maximum values**

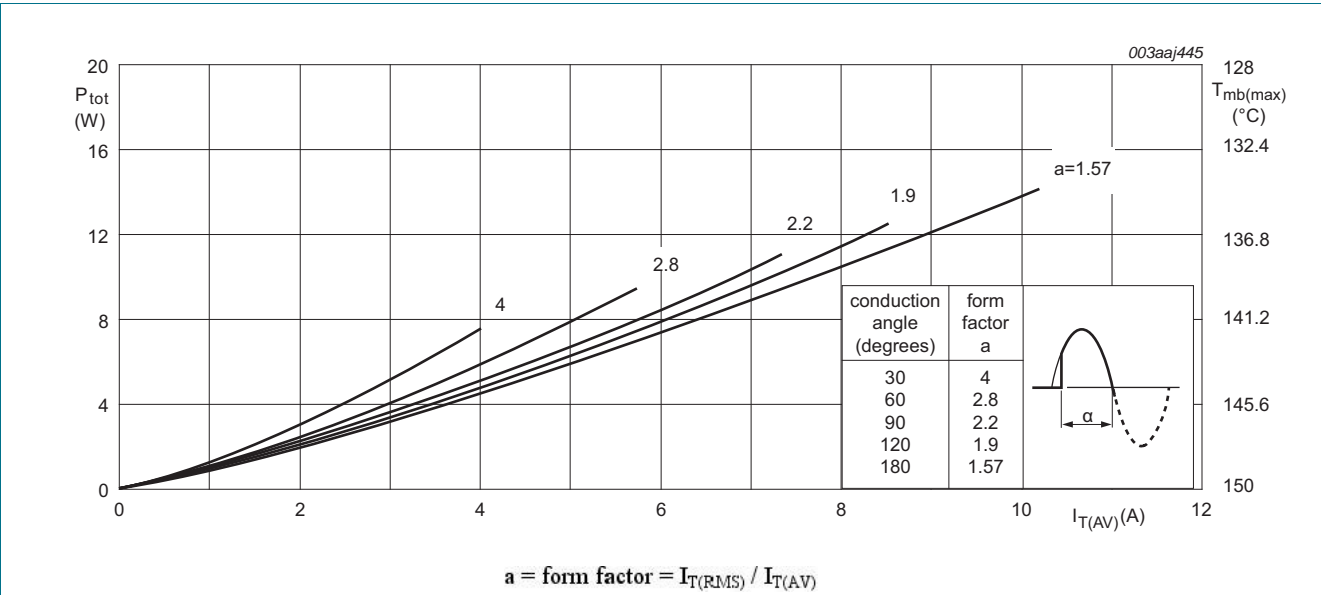


Fig 3. Total power dissipation as a function of average on-state current; maximum values

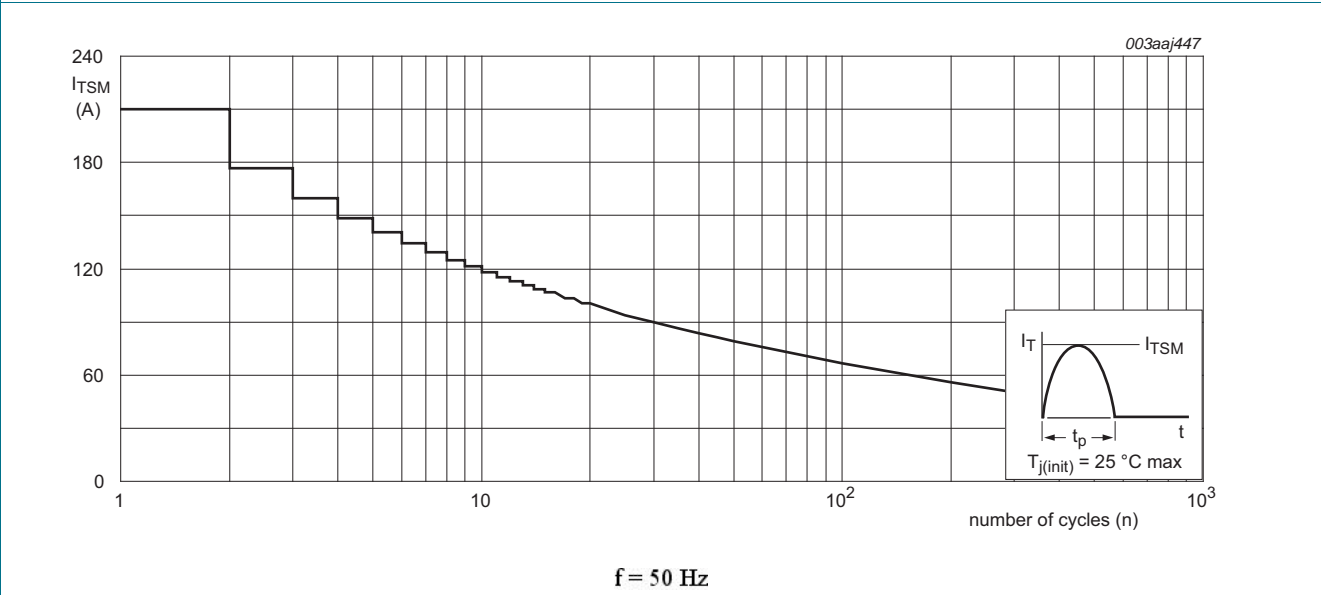
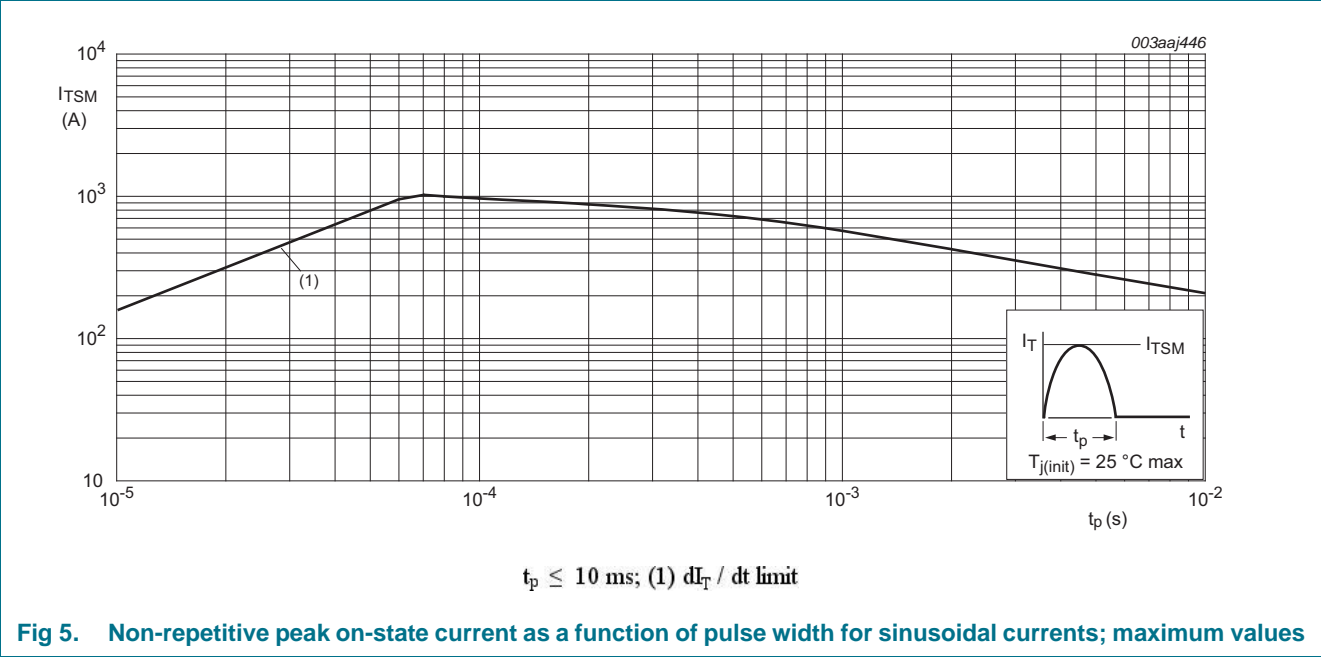


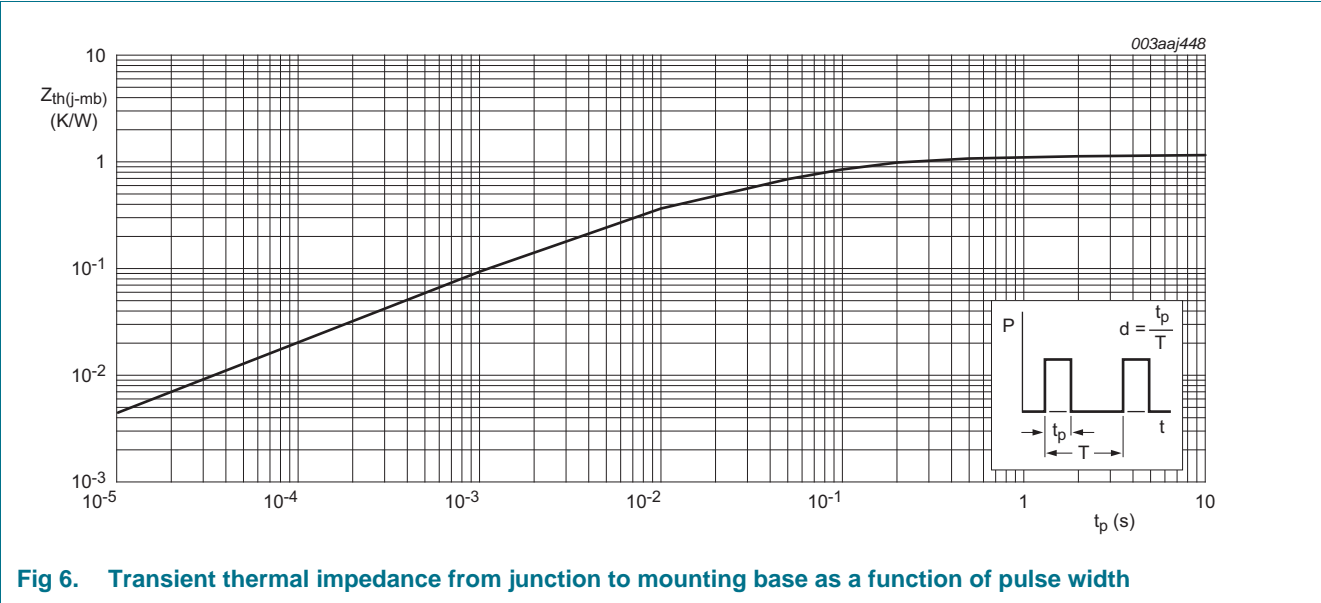
Fig 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



5. Thermal characteristics

Table 5. Thermal characteristics

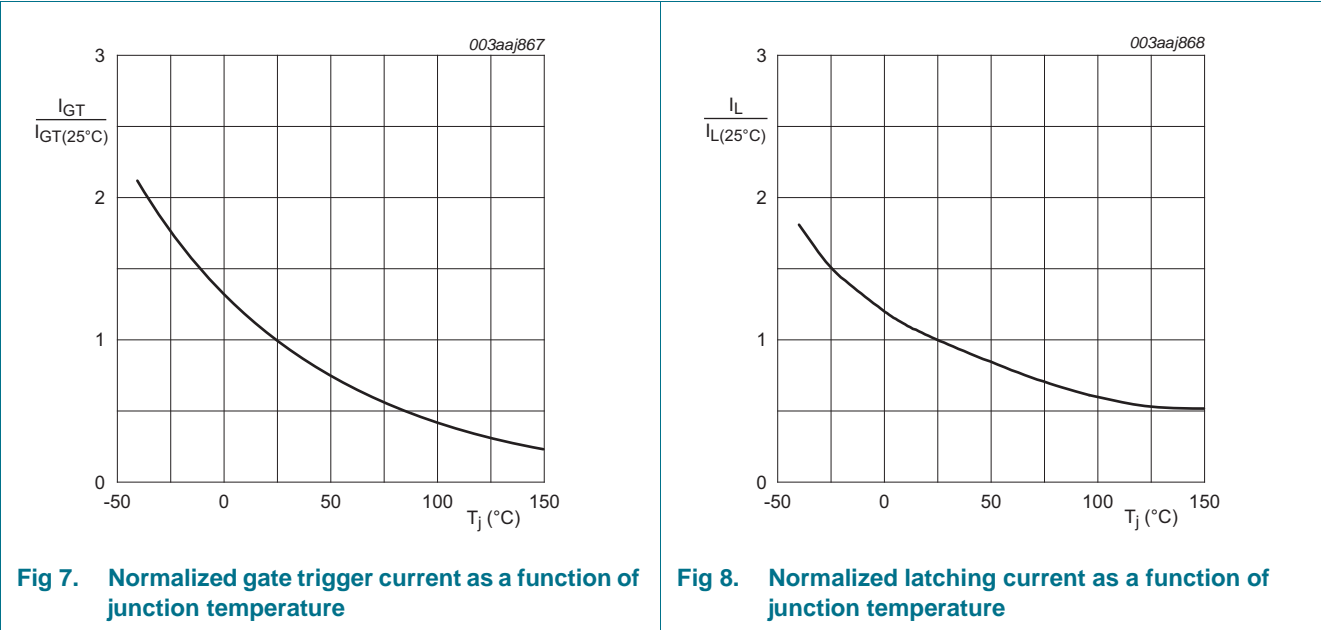
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see <a href="#">Figure 6</a>	-	-	1.1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 7</a>	-	4.5	25	mA
$I_L$	latching current	$V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 8</a>	-	21	60	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 9</a>	-	16	40	mA
$V_T$	on-state voltage	$I_T = 32\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 10</a>	-	1.2	1.5	V
$V_{GT}$	gate trigger voltage	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 11</a>	-	0.7	1.3	V
		$V_D = 400\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 11</a>	0.2	0.4	-	V
$I_D$	off-state current	$V_D = 600\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	-	0.2	1	mA
$I_R$	reverse current	$T_j = 150\text{ }^{\circ}\text{C}$ ; $V_R = 600\text{ V}$	-	0.2	1	mA
Dynamic characteristics						
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 402\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform; gate open circuit	300	-	-	V/ $\mu\text{s}$



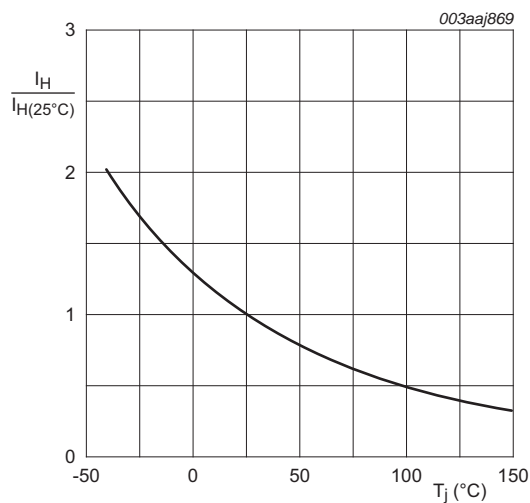
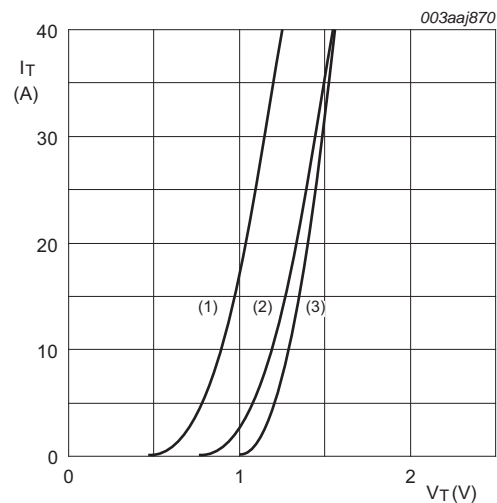


Fig 9. Normalized holding current as a function of junction temperature



$V_o = 1.0336 \text{ V}; R_s = 0.0141 \Omega$   
(1)  $T_J = 150^\circ\text{C}$ ; typical values  
(2)  $T_J = 150^\circ\text{C}$ ; maximum values  
(3)  $T_J = 25^\circ\text{C}$ ; maximum values

Fig 10. On-state current as a function of on-state voltage

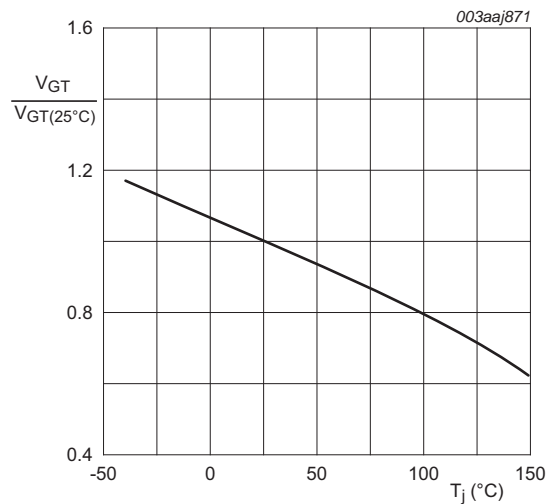


Fig 11. Normalized gate trigger voltage as a function of junction temperature



7. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78

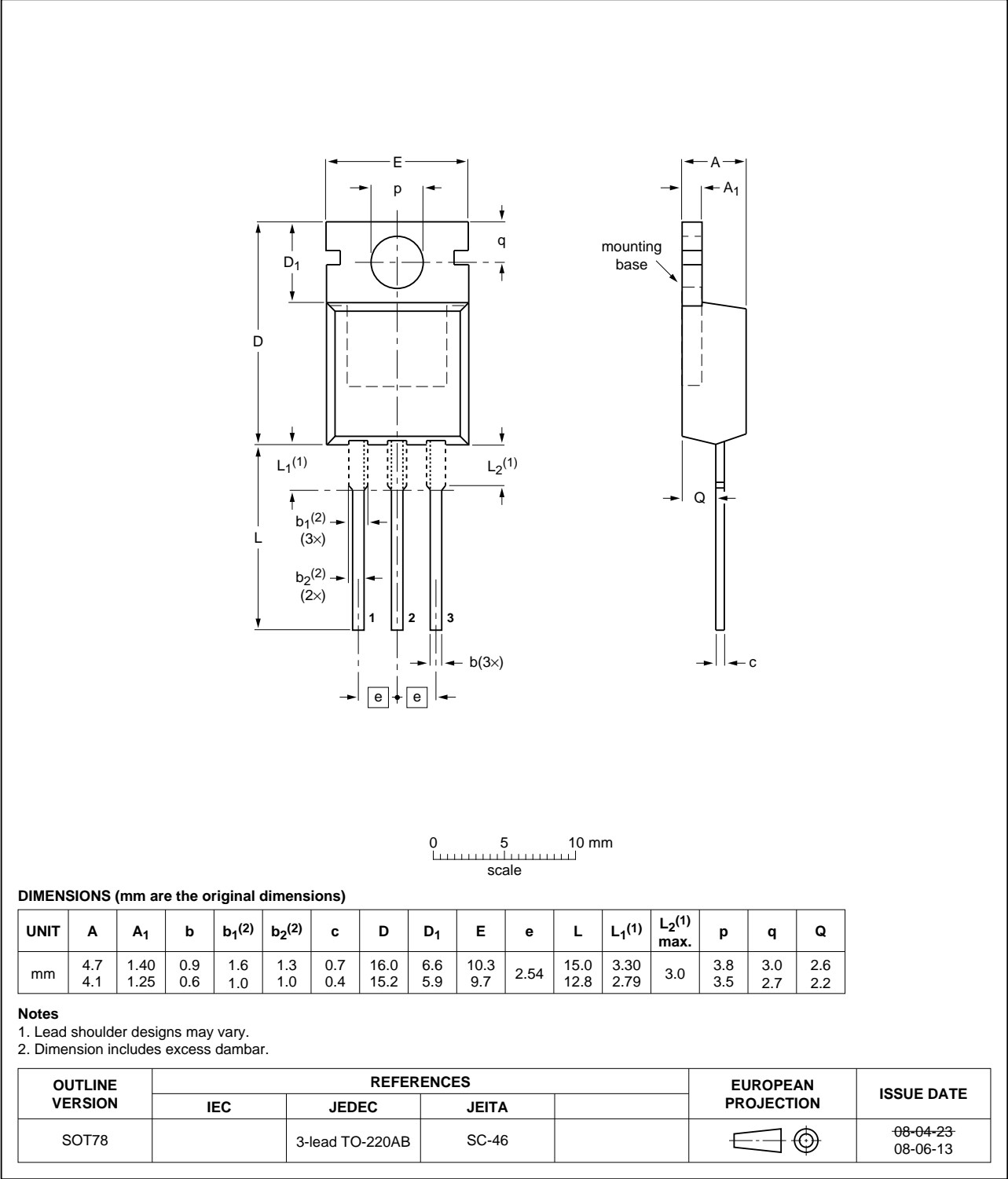


Fig 12. TO-220AB (SOT78)

## 8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TYN16-600RT v.1	20120702	Product data sheet	-	-

## 9. Legal information

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Document status <sup>[1] [2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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